NSN 5962-01-122-6970

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-122-6970

Body Length:	
0.925 inches	
Body Width:	
0.302 inches	
Body Height:	
0.175 inches	
Maximum Power Dissip	ation Rating:
409.6 milliwatts	
Operating Tempurature	Range:
+0.0/+75.0 degrees celsi	us
Storage Tempurature R	ange:
-65.0/+150.0 degrees cel	sius
Features Provided:	
Hermetically sealed and	programmable and bipolar and 3-state output and w/enable
Inclosure Material:	
Ceramic	
Inclosure Configuration	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
12 input	
Terminal Surface Treat	nent:
Solder	
Voltage Rating And Typ	e Per Characteristic:
7.0 volts power source	
Time Rating Per Chacte	ristic:
40.00 nanoseconds prop	pagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Terminal Type And Qua	intity:
18 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	
Fiig:	
A458a0	